## Amendments to the Claims:

The following listing of claims will replace all prior versions, and listings, of claims in the application:

- 1. (Currently Amended) A thin film transistor including a plurality of component parts, comprising:
  - a channel region;
  - a gate electrode opposed to the channel region;
- a gate insulating film provided between the channel region and the gate electrode;
  - a source-drain region connected to said channel region;
  - a source-drain wiring layer electrically connected to said source-drain region;
  - a gate wiring layer electrically connected to said gate electrode,
- an extension of the gate electrode extending outwardly above and outside of the channel region.
- 2. (Currently Amended) A thin film transistor including a plurality of component parts, comprising:
  - a channel region;
  - a gate electrode opposed to the channel region;
- a gate insulating film provided between the channel region and the gate electrode;
  - a source-drain region connected to said channel region;
  - a source-drain wiring layer electronically connected to said source-drain region;
  - a gate wiring layer electrically connected to said gate electrode,
- an extensions extending from at least one end both ends of the gate electrode outside of the channel region and along a channel lengthlongitudinal direction.

- 3. (Currently Amended) The thin film transistor according to claim 1, the extension extending in two directions from a central portion both ends of the gate electrode along a channel length direction.
- 4. (Original) The thin film transistor according to claim 3, the gate wiring layer being electrically connected to the extension of the at least one end of the gate electrode through a plurality of contact holes.
- 5. (Original) A CMOS inverter circuit comprising two of the thin film transistors according to claim 1, the thin film transistors having an inverse conductivity type from each other, adjacent source-drain regions of said thin film transistors being connected.
- 6. (Original) A display device comprising a driving circuit including a thin film transistor according to claim 1.
- 7. (Original) An electronic apparatus comprising a display device as defined in claim 6.